## 35 V, 5 A, Low V<sub>CE(sat)</sub> PNP Transistor

ON Semiconductor's  $e^2$ PowerEdge family of low  $V_{CE(sat)}$  transistors are miniature surface mount devices featuring ultra low saturation voltage ( $V_{CE(sat)}$ ) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical application are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

#### **Features**

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant\*

#### MAXIMUM RATINGS (T<sub>A</sub> = 25°C)

Rating	Symbol	Max	Unit
Collector-Emitter Voltage	$V_{CEO}$	-35	Vdc
Collector-Base Voltage	$V_{CBO}$	-55	Vdc
Emitter-Base Voltage	$V_{EBO}$	-5.0	Vdc
Collector Current - Continuous	I <sub>C</sub>	-2.0	Adc
Collector Current - Peak	I <sub>CM</sub>	-5.0	Α
Electrostatic Discharge	ESD	HBM Class 3 MM Class C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.



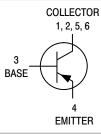
#### ON Semiconductor®

http://onsemi.com

# \$ 5.0 AMPS PNP LOW $V_{CE(sat)}$ TRANSISTOR EQUIVALENT $R_{DS(on)}$ 100 $m\Omega$



TSOP-6 CASE 318G STYLE 6



#### **MARKING DIAGRAM**



VS8 = Device Code

M = Date Code\*

• = Pb-Free Package

(\*Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NSS35200MR6T1G	TSOP-6 (Pb-Free)	3,000 / Tape & Reel
SNSS35200MR6T1G	TSOP-6 (Pb-Free)	3,000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation  T <sub>A</sub> = 25°C  Derate above 25°C	P <sub>D</sub> (Note 1)	625 5.0	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub> (Note 1)	200	°C/W
Total Device Dissipation  T <sub>A</sub> = 25°C  Derate above 25°C	P <sub>D</sub> (Note 2)	1.0 8.0	W mW/°C
Thermal Resistance, Junction-to-Ambient	R <sub>θJA</sub> (Note 2)	120	°C/W
Thermal Resistance, Junction-to-Lead #1	$R_{ hetaJL}$	80	°C/W
Total Device Dissipation (Single Pulse < 10 sec.)	P <sub>Dsingle</sub> (Notes 2 & 3)	1.75	W
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	-55 to +150	°C

<sup>1.</sup> FR-4 @ Minimum Pad. 2. FR-4 @ 1.0 X 1.0 inch Pad. 3. Refer to Figure 8.

#### **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Typical	Max	Unit
OFF CHARACTERISTICS	•		•	•	•
Collector – Emitter Breakdown Voltage ( $I_C = -10$ mAdc, $I_B = 0$ )	V <sub>(BR)CEO</sub>	-35	-45	_	Vdc
Collector – Base Breakdown Voltage $(I_C = -0.1 \text{ mAdc}, I_E = 0)$	V <sub>(BR)CBO</sub>	-55	-65	-	Vdc
Emitter – Base Breakdown Voltage $(I_E = -0.1 \text{ mAdc}, I_C = 0)$	V <sub>(BR)EBO</sub>	-5.0	-7.0	-	Vdc
Collector Cutoff Current (V <sub>CB</sub> = -35 Vdc, I <sub>E</sub> = 0)	I <sub>CBO</sub>	-	-0.03	-0.1	μAdc
Collector-Emitter Cutoff Current (V <sub>CES</sub> = -35 Vdc)	I <sub>CES</sub>	-	-0.03	-0.1	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = -4.0 Vdc)	I <sub>EBO</sub>	-	-0.01	-0.1	μAdc
ON CHARACTERISTICS	-		•		
DC Current Gain (Note 4) ( $I_C = -1.0 \text{ A}, V_{CE} = -1.5 \text{ V}$ ) ( $I_C = -1.5 \text{ A}, V_{CE} = -1.5 \text{ V}$ ) ( $I_C = -2.0 \text{ A}, V_{CE} = -3.0 \text{ V}$ )	h <sub>FE</sub>	100 100 100	200 200 200	- 400 -	
Collector – Emitter Saturation Voltage (Note 4) ( $I_C = -0.8 \text{ A}, I_B = -0.008 \text{ A}$ ) ( $I_C = -1.2 \text{ A}, I_B = -0.012 \text{ A}$ ) ( $I_C = -2.0 \text{ A}, I_B = -0.02 \text{ A}$ )	V <sub>CE(sat)</sub>	- - -	-0.125 -0.175 -0.260	-0.15 -0.20 -0.31	V
Base – Emitter Saturation Voltage (Note 4) $(I_C = -1.2 \text{ A}, I_B = -0.012 \text{ A})$	V <sub>BE(sat)</sub>	-	-0.68	-0.85	V
Base – Emitter Turn–on Voltage (Note 4) $(I_C = -2.0 \text{ A, } V_{CE} = -3.0 \text{ V})$	V <sub>BE(on)</sub>	-	-0.81	-0.875	V
Cutoff Frequency ( $I_C = -100 \text{ mA}$ , $V_{CE} = -5.0 \text{ V}$ , $f = 100 \text{ MHz}$ )	f <sub>T</sub>	100	_	-	MHz
Input Capacitance (V <sub>EB</sub> = -0.5 V, f = 1.0 MHz)	Cibo	-	600	650	pF
Output Capacitance (V <sub>CB</sub> = -3.0 V, f = 1.0 MHz)	Cobo	-	85	100	pF
Turn-on Time ( $V_{CC}$ = -10 V, $I_{B1}$ = -100 mA, $I_{C}$ = -1 A, $R_{L}$ = 3 $\Omega$ )	t <sub>on</sub>	-	35	-	nS
Turn-off Time ( $V_{CC}$ = -10 V, $I_{B1}$ = $I_{B2}$ = -100 mA, $I_{C}$ = 1 A, $R_{L}$ = 3 $\Omega$ )	t <sub>off</sub>	-	225	-	nS

<sup>4.</sup> Pulsed Condition: Pulse Width = 300  $\mu$ sec, Duty Cycle  $\leq$  2%.

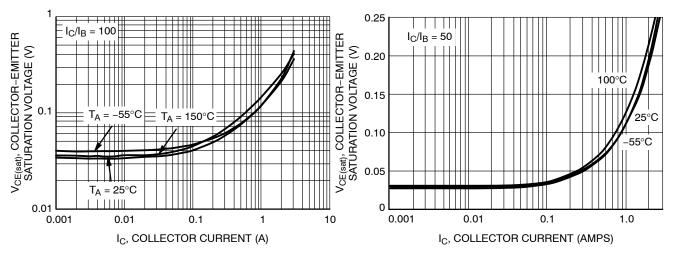


Figure 1. Collector Emitter Saturation Voltage versus Collector Current

Figure 2. Collector Emitter Saturation Voltage versus Collector Current

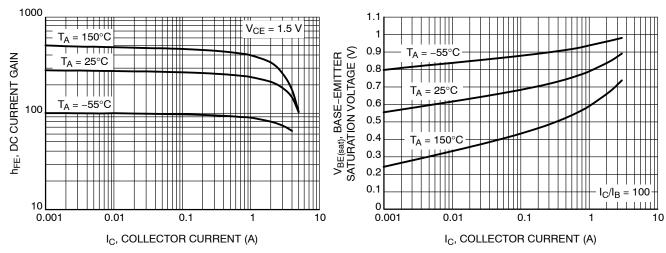


Figure 3. DC Current Gain versus Collector Current

Figure 4. Base Emitter Saturation Voltage versus Collector Current

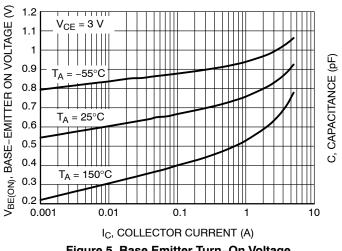


Figure 5. Base Emitter Turn-On Voltage versus Collector Current

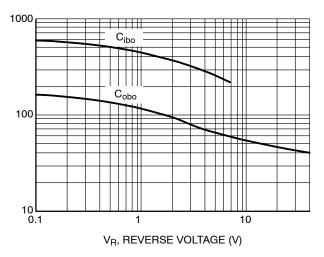


Figure 6. Capacitance

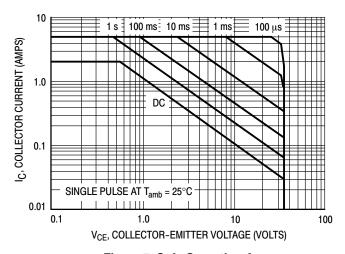


Figure 7. Safe Operating Area

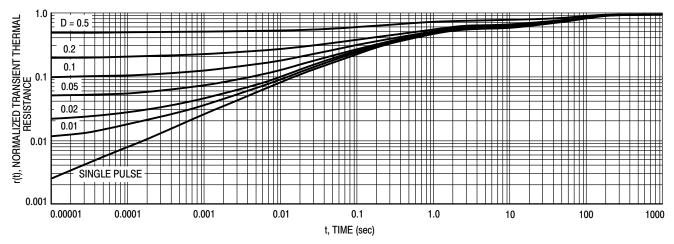
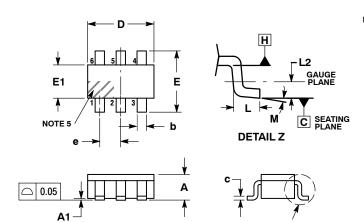


Figure 8. Normalized Thermal Response

#### PACKAGE DIMENSIONS

#### TSOP-6 CASE 318G-02 ISSUE V



#### NOTES:

- 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

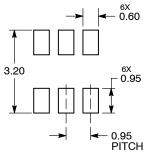
- DIMENSIONING AND TOLERANCING PER ASME 114.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM
  LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
  DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH,
  PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR
  GATE BURRS SHALL NOT EXCEED 0.15 PER SIDE. DIMENSIONS D AND E1 ARE DETERMINED AT DATUM H.
- PIN ONE INDICATOR MUST BE LOCATED IN THE INDICATED ZONE.

	MILLIMETERS			
DIM	MIN	NOM	MAX	
Α	0.90	1.00	1.10	
A1	0.01	0.06	0.10	
b	0.25	0.38	0.50	
С	0.10	0.18	0.26	
D	2.90	3.00	3.10	
E	2.50	2.75	3.00	
E1	1.30	1.50	1.70	
е	0.85	0.95	1.05	
L	0.20	0.40	0.60	
L2	0.25 BSC			
М	0°	-	10°	

- STYLE 6: PIN 1. COLLECTOR
  - 2. COLLECTOR 3. BASE 4. EMITTER

  - COLLECTOR

#### **RECOMMENDED** SOLDERING FOOTPRINT\*



**DIMENSIONS: MILLIMETERS** 

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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